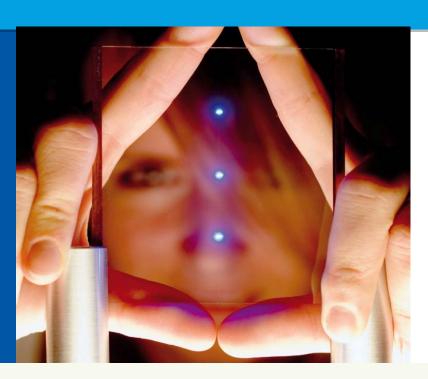


**HUMAN HEALTH | ENVIRONMENTAL HEALTH** 



PerkinElmer Products and Developments for Astrophysics

Arthur Barlow, Henri Dautet, Juergen Schilz

ASPERA Technology Forum, Munich 21-22 Oct. 2010

**PKI** Confidential

# PerkinElmer is a \$1.8 Billion technology leader...



### HUMAN HEALTH | ENVIRONMENTAL HEALTH













# Global Technology Leader

- Mission driven: Better outcomes
- Creating a healthier, cleaner and safer environment

# Company Facts and Figures

- \$1.8 Billion in 2009 revenues
- 8400 employees worldwide
- Operations in 150 countries
- \$120 million in annual R&D investment
- Publicly traded (NYSE: PKI)

## Organized under two groups:

- Human Health
- Environmental Health

# PerkinElmer Environmental Health &IDS



# Environmental Health Illumination & Detection Solutions - IDS Defense Illumination Analytical Sciences & Lab Service - ASLS Illumination

- On August 31, 2010, PerkinElmer announced the signing of a Definitive Agreement with Veritas Capital for the purchase of the Illumination and Detection Solutions Business.
- •PerkinElmer expects the sale to be completed by the end of 2010
- •Illumination and Detection Solutions business will be an independent company with a different name.
- IDS will **continue** to be one of the world's leading optoelectronics solutions providers in the market today with a continuing commitment to innovative, technology-based OEM solutions.



### IDS Detection--- Overview



# Highlights

- 7 global manufacturing and R&D sites, USA, Canada, Asia, EU
- Largest supplier of thermopile infrared sensors
- Innovative product offering such as smart digital pyroelectric sensors
- ➤ Leader in low light level detection (L³D) and infrared sensing

### **Product Lines**

Infrared Sensing

> Pyroelectric Sensors

> Thermopiles

### Photon Detection

- ➤ Avalanche Photodiodes
- ➤ Photodiodes & Arrays
- > Channel Photomultipliers
- > Single Photon Counting Modules
- > CCDs
- ➤ Photocells

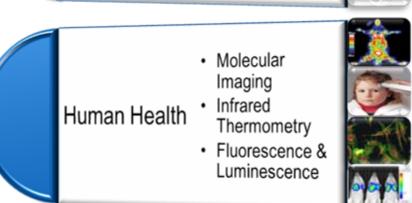


Safety and Security

- Intrusion Alarm
- Smoke Detection
- X-Ray Security Inspection

Energy Conservation

- Proximity Light Switching
- Presence Detection
- Dusk-to Dawn Light Switching

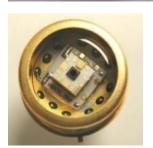


# IDS background



 Wide portfolio of opto-solutions (detectors: from UV to IR; emitters) single elements, arrays, modules...

- For low light level detection:
  - LLAM (Low Light Amplifier Module)
     Various detectors with hybrid amplifier for optimum NEP.
  - SPCM (Single Photon Counting Module)
     Uses Slik™ APD on double stage TEC
  - World's best performances (500nm to 1060nm)
     Dark count selection from <20cps to <500cps at -10°C</li>
     Maximum counting rate ~30MHz
     Single photon detection probability ~70%





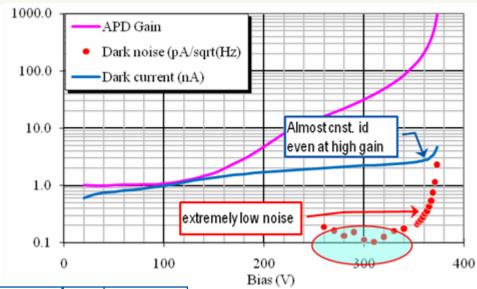
## New "UV" line of detectors (1)



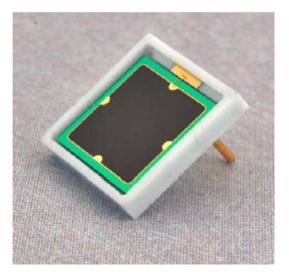
UV – APD (available now)

Large area (active area 5.6 x 5.6 mm)

World's best performance in its size



Symbol	Parameter	C30739ECERH (standard version)			C30739ECERH-1 (low gain version)			C30739ECERH-2 (high gain version)				
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Conditions
$V_{br}$	Breakdown Voltage	-	400	450	-	390	450	-	400	450	٧	
d∨	$dV = V_{br} - V_{op}$	-	25	-	-	40	-	-	10	-	٧	defines Operating Voltage V <sub>op</sub>
М	Gain at V₀p	100	150	-	30	50	-	200	250	-		
Q.E.	Quantum Efficiency	60	75	-	60	75	-	60	75	-	%	at 430 nm
R	Responsivity	-	39	-	-	13	-	-	65	-	A/W	at 430 nm and typ. Gain M
CJ	Capacitance	-	60	-	-	60	-	-	60	-	рF	at V₀p
t <sub>R</sub>	Rise Time	-	2	-	-	2	-	-	2	-	ns	
I <sub>D</sub>	Dark Current	-	3	-	-	3	-	-	3	-	nΑ	at V₀p
I <sub>N</sub>	Noise Current	-	0.4	-	-	0.4	-	-	0.5	-	pA/√ Hz	at V <sub>op</sub>



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# New "UV" line of detectors (2)



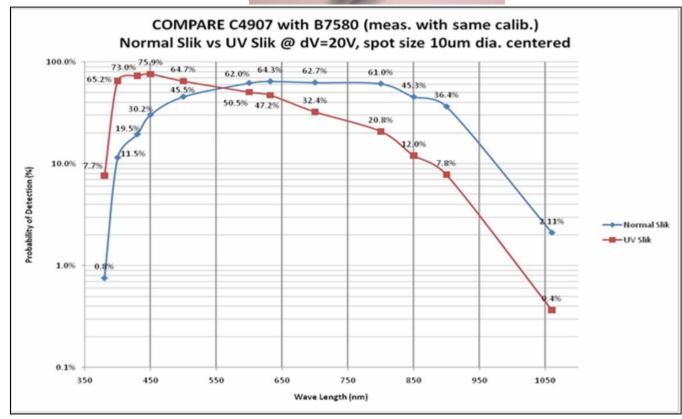
# UV – SPCM (Preliminary results):

- Chip is UV Slik™
- Dark counts~ 50cps at -8°C
- PDE at 420nm ~75%.





Samples available soon



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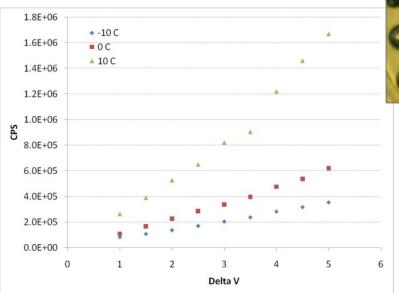
# In development: UV – SiPM

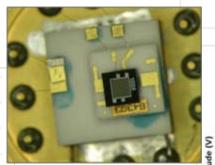


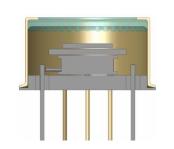
- PKI MEPHI Collaboration (ongoing)
- SiPM (various designs) in preparation
- Accent on low cross-talk, high PDE, low dark count First prototypes completed Characterisation in progress, chip on one stage TEC.

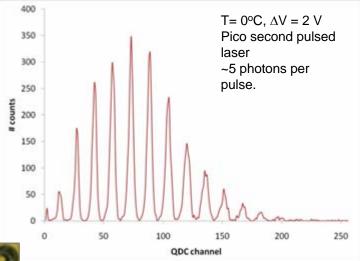
Samples available shortly

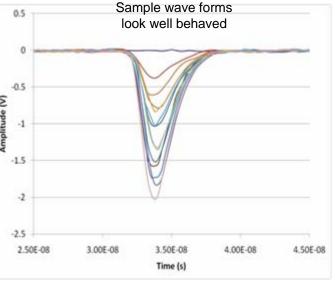
Production in 2011







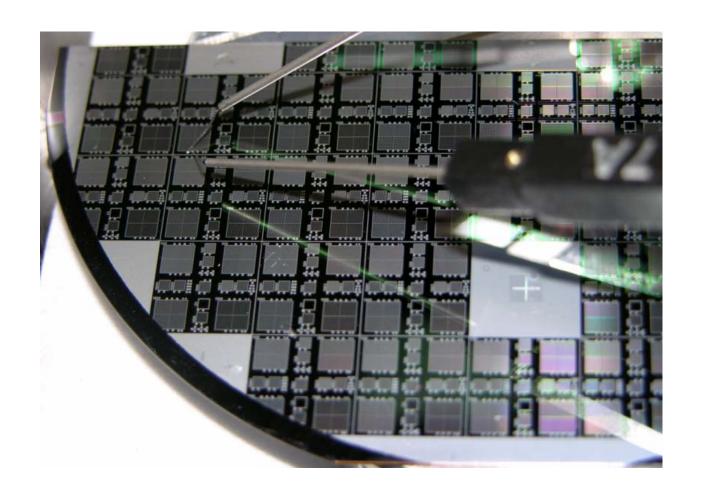




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# Testing a PKI-MEPHI UV-SiPM wafer





# Other developments



- 3D assembly of APD arrays in linear mode (XNAP project)
  - In progress: Still some development required, but process expected to be fully developed by Q1-2011
- 3D assembly of SiPM (including micro-pixel addressing and active quenching)
  - Exploring a program starting with Engineering Department of Université de Sherbrooke
- Would consider proposals for new detectors in new projects...

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